

# 7.0 V to 26.0 V Input, 1 A Integrated MOSFET Single Synchronous Buck DC/DC Converter

# BD9E104FJ

#### **General Description**

BD9E104FJ is a synchronous buck DC/DC converter with built-in low on-resistance power MOSFETs. High efficiency at light load with a SLLM<sup>TM</sup> (Simple Light Load Mode). It is most suitable for use in the equipment to reduce the standby power is required. It is a current mode control DC/DC converter and features high-speed transient response. Phase compensation can also be set easily.

#### **Features**

- SLLM<sup>TM</sup> Control (Simple Light Load Mode)
- Single Synchronous Buck DC/DC converter
- Over Current Protection
- Short Circuit Protection
- Thermal Shutdown Protection
- Under Voltage Lockout Protection
- Internal Soft Start
- Reduce External Diode
- SOP-J8 Package

# **Applications**

- Consumer Applications such as Home Appliance
- Secondary Power Supply and Adapter Equipment
- Telecommunication Devices

# **Key Specifications**

■ Input Voltage Range: 7.0 V to 26.0 V

■ Output Voltage Range: 1.0 V to V<sub>IN</sub> x 0.5 V

Output Current: 1.0 A (Max)

Switching Frequency: 570 kHz (Typ)
 High Side MOSFET ON-Resistance:250 mΩ (Typ)

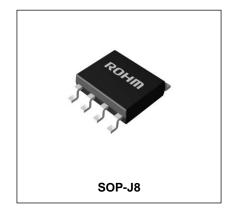
Low Side MOSFET ON-Resistance: 200 mΩ (Typ)

Shutdown Current: 0 μA (Typ)

#### Package SOP-J8

# W(Typ) x D(Typ) x H(Max)

4.90mm x 6.00mm x 1.65mm



#### **Typical Application Circuit**

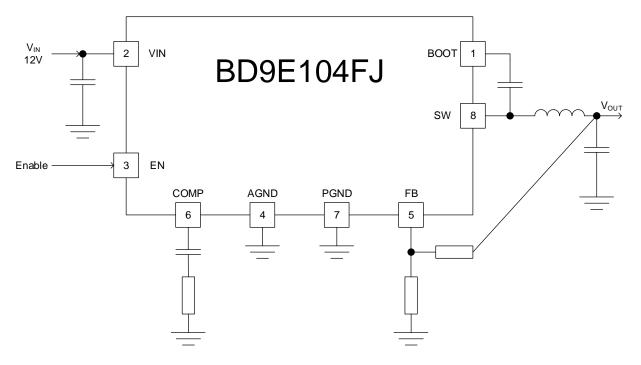


Figure 1. Application Circuit

SLLM<sup>TM</sup> is a trademark of ROHM Co., Ltd.

OProduct structure: Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays

# **Pin Configuration**

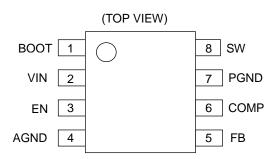


Figure 2. Pin Configuration

# **Pin Descriptions**

• :	2000: .pt.:0:					
	Pin No.	Pin Name	Description			
	1	воот	Connect a bootstrap capacitor of 0.1 µF between this pin and the SW pin. The voltage of this capacitor is the gate drive voltage of the High Side MOSFET.			
	2	VIN	Power supply pin for the switching regulator and control circuit.			
	3	EN	Turning this pin signal low-level (0.8 V or lower), the device is forced to be in the shutdown mode. Turning this pin signal high-level (2.5 V or higher) enables the device. This pin must be terminated.			
	4	AGND	Ground pin for the control circuit.			
		FB	Inverting input node for the gm error amplifier. See page 21 for how to calculate the resistance of the output voltage setting.			
-	6	COMP	Input pin for the gm error amplifier output and the output for the PWM comparator.  Connect phase compensation components to this pin.  See page 22 for how to calculate the resistance and capacitance for phase compensation.			
	7	PGND	Ground pin for the output stage of the switching regulator.			
Ī	8	SW	Switch pin. This pin is connected to the source of the High Side MOSFET and drain of the Low Side MOSFET. Connect a bootstrap capacitor of 0.1 µF between this pin and the BOOT pin. In addition, connect an inductor considering the direct current superimposition characteristic.			

# **Block Diagram**

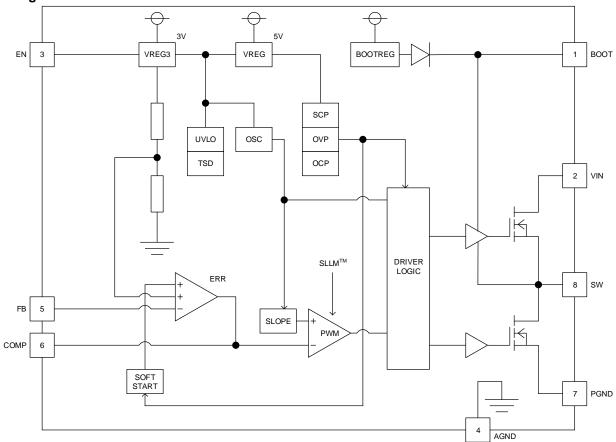


Figure 3. Block Diagram

#### **Description of Blocks**

#### VREG3

Block creating internal reference voltage 3 V (Typ).

#### VREG

Block creating internal reference voltage 5 V (Typ).

#### BOOTREG

Block creating gate drive voltage.

#### TSD

The TSD block is for thermal protection. It shuts down the device when the internal temperature of IC rises to 175 °C (Typ) or higher. Thermal protection circuit resets when the temperature falls. The circuit has a hysteresis of 25 °C (Typ).

#### UVLO

This is under voltage lockout block. It shuts down the device when the VIN pin voltage falls to 6.4V (Typ) or less. The UVLO threshold voltage has a hysteresis of 200mV (Typ).

#### ERR

The ERR amplifier compares the reference voltage with the feedback voltage of the output voltage. The ERR amplifier output voltage (the COMP pin voltage) determine the switching duty. Also, the COMP pin voltage is limited by internal slope voltage due to soft start function during start-up.

#### OSC

Block generating oscillation frequency.

#### SLOPE

Creates delta wave from clock, generated by OSC, and sends voltage composed by current sense signal of High Side MOSFET and delta wave to PWM comparator.

#### PWM

Settles the switching duty by comparing the output COMP pin voltage of ERR amplifier and signal of SLOPE block.

#### DRIVER LOGIC

This is DC/DC driver block. Input signal from PWM and drives MOSFET.

#### SOFT START

By controlling current, output voltage starts calmly preventing over shoot of output voltage and inrush current.

#### OCP

Current flowing in High Side MOSFET is controlled one cycle each of switching frequency when over current occurs.

#### SCP

When the FB pin voltage has fallen below 0.56 V (Typ) and remained there for 0.9ms (Typ), SCP stops the operation for 14.4 ms (Typ) and subsequently initiates a restart.

#### OVP

When the FB pin voltage exceeds 1.04 V (Typ), it turns MOSFET of output part MOSFET OFF. After output voltage dropped, it returns to normal operation with hysteresis.

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Unit
Input Voltage	V <sub>IN</sub>	-0.3 to +30.0	V
EN Pin Voltage	Ven	-0.3 to +30.0	V
Voltage from GND to BOOT	V <sub>воот</sub>	-0.3 to +35.0	V
Voltage from SW to BOOT	$\Delta V_{BOOT}$	-0.3 to +7.0	V
FB Pin Voltage	V <sub>FB</sub>	-0.3 to +7.0	V
COMP Pin Voltage	VCOMP	-0.3 to +7.0	V
SW Pin Voltage	Vsw	-0.5 to +30.0	V
Maximum Junction Temperature	Tjmax	150	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

# Thermal Resistance<sup>(Note 1)</sup>

Deremeter	Cumbal	Thermal Res	l limit	
Parameter	Symbol	1s <sup>(Note 3)</sup>	2s2p <sup>(Note 4)</sup>	Unit
SOP-J8				
Junction to Ambient	θја	149.3	76.9	°C/W
Junction to Top Characterization Parameter <sup>(Note 2)</sup>	$\Psi_{JT}$	18	11	°C/W

<sup>(</sup>Note 1) Based on JESD51-2A(Still-Air)..

Layer Number of Measurement Board	Material	Board Size			
Single	FR-4	114.3mm x 76.2mm x	1.57mmt		
Тор					
Copper Pattern	Thickness				
Footprints and Traces	70µm				
Layer Number of Measurement Board	Material	Board Size			
4 Layers	FR-4	114.3mm x 76.2mm	x 1.6mmt		
Тор		2 Internal Laye	ers	Bottom	
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern	Thickness
Footprints and Traces	70µm	74.2mm x 74.2mm	35µm	74.2mm x 74.2mm	70µm

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB boards with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

<sup>(</sup>Note 2)The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.

(Note 3) Using a PCB board based on JESD51-3.

(Note 4) Using a PCB board based on JESD51-7.

**Recommended Operating Ratings** 

Parameter	Symbol		- Unit		
r arameter		Min	Тур	Max	Offic
Input Voltage	V <sub>IN</sub>	7.0	-	26.0	V
Operating Temperature	Topr	-40	-	+85 <sup>(Note 1)</sup>	°C
Output Current	Гоит	-	-	1.0	Α
Output Voltage Range	V <sub>RANGE</sub>	1.0 <sup>(Note 2)</sup>	-	VIN×0.5	V

Electrical Characteristics (Unless otherwise specified Ta=25°C, V<sub>IN</sub>=12V, V<sub>EN</sub>=3V)

Devementes	Comple ed	Limits			l loit	Conditions	
Parameter	Symbol	Min	Тур	Max	Unit	Conditions	
Operating Supply Current	I <sub>OPR</sub>	-	250	500	μΑ	V <sub>FB</sub> =0.9 V	
Shutdown Current	I <sub>SD</sub>	-	0	10	μΑ	V <sub>EN</sub> =0 V	
FB Pin Voltage	V <sub>FB</sub>	0.784	0.800	0.816	V		
FB Input Current	I <sub>FB</sub>	-1	0	+1	μΑ	V <sub>FB</sub> =0.8 V	
Switching Frequency	fosc	484	570	656	kHz		
High Side MOSFET ON-Resistance	Ronh	-	250	-	mΩ	Isw=100 mA	
Low Side MOSFET ON-Resistance	Ronl	-	200	-	mΩ	Isw=100 mA	
Over Current limit <sup>(Note 3)</sup>	Ішміт	2.1	2.4	2.7	Α	Without switching	
UVLO Threshold Voltage	$V_{UVLO}$	6.1	6.4	6.7	V	V <sub>IN</sub> falling	
UVLO Hysteresis Voltage	Vuvlohys	100	200	300	mV		
EN ON Threshold Voltage	V <sub>ENH</sub>	2.5	-	Vin	V		
EN OFF Threshold Voltage	V <sub>ENL</sub>	0	-	0.8	V		
EN Input Current	I <sub>EN</sub>	2	4	8	μΑ	V <sub>EN</sub> =3 V	
Soft Start Time	tss	1.2	2.5	5.0	ms		

(Note 3) No tested on outgoing inspection.

<sup>(</sup>Note 1) Tj must be lower than 150°C under actual operating environment.
(Note 2) Please use it in output voltage setting of which output pulse width does not become 250 ns (Typ) or less.
See the page 21 for how to calculate the resistance of the output voltage setting.

# **Typical Performance Curves**

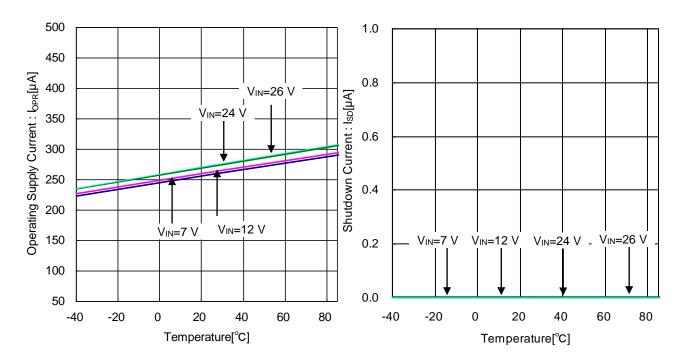


Figure 4. Operating Supply Current vs Temperature

Figure 5. Shutdown Current vs Temperature

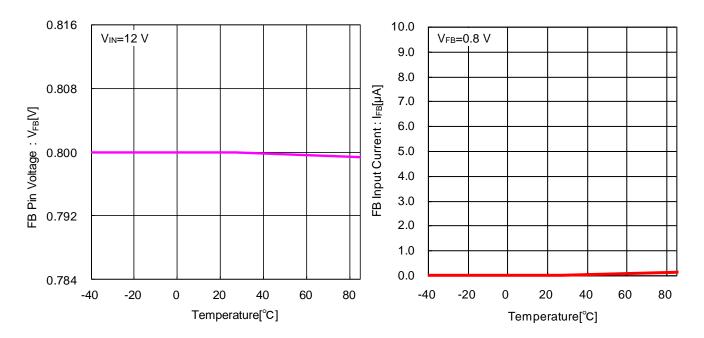
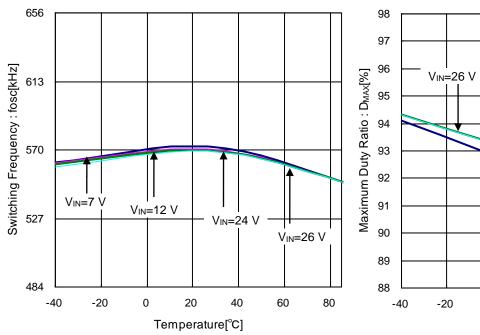


Figure 6. FB Pin Voltage vs Temperature

Figure 7. FB Input Current vs Temperature

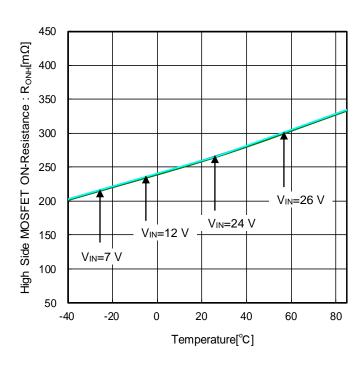
#### **Typical Performance Curves - continued**



98 97 96 97 98 97 98 99 90 89 90 89 89 40 -20 0 20 40 60 80 Temperature[°C]

Figure 8. Switching Frequency vs Temperature

Figure 9. Maximum Duty Ratio vs Temperature



Low Side MOSFET ON-Resistance :  $R_{\text{ONL}}[m\Omega]$ 350 300 250 200 VIN=26 V 150 V<sub>IN</sub>=24 V V<sub>IN</sub>=12 V 100 V<sub>IN</sub>=7 V 50 0 -20 0 20 40 -40 60 80 Temperature[°C]

Figure 10. High Side MOSFET ON-Resistance vs Temperature

Figure 11. Low Side MOSFET ON-Resistance vs Temperature

400

# **Typical Performance Curves - continued**

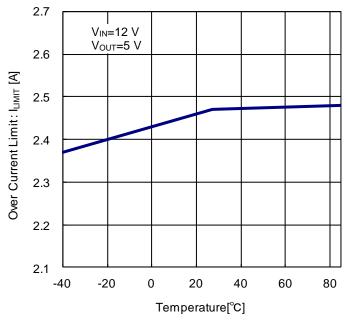


Figure 12. Over Current Limit vs Temperature

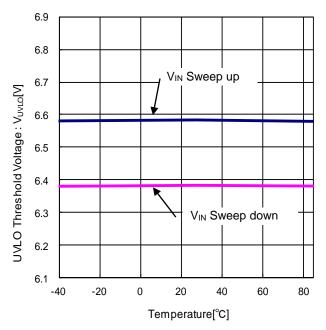


Figure 13. UVLO Threshold Voltage vs Temperature

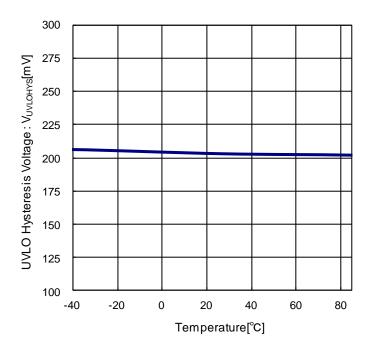


Figure 14. UVLO Hysteresis Voltage vs Temperature

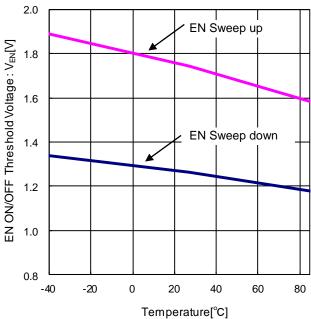


Figure 15. EN ON/OFF Threshold Voltage vs Temperature

# **Typical Performance Curves - continued**

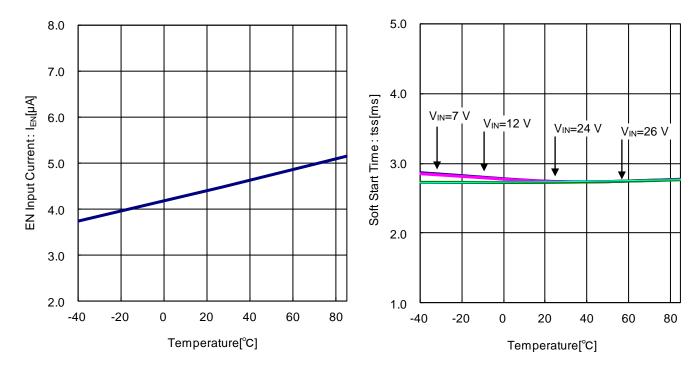


Figure 16. EN Input Current vs Temperature

Figure 17. Soft Start Time vs Temperature

# **Typical Performance Curves (Application)**

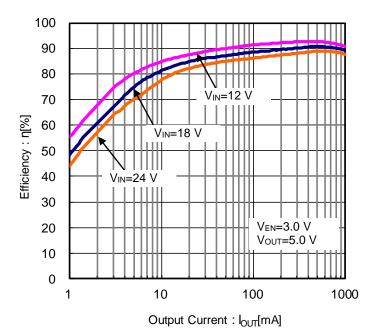


Figure 18. Efficiency vs Output Current (V<sub>OUT</sub>=5.0 V)

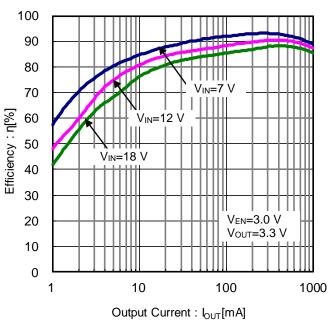


Figure 19. Efficiency vs Output Current (V<sub>OUT</sub>=3.3 V)

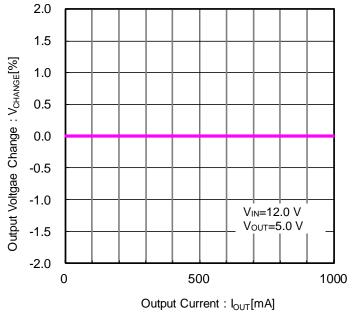


Figure 20. V<sub>OUT</sub> Load Regulation

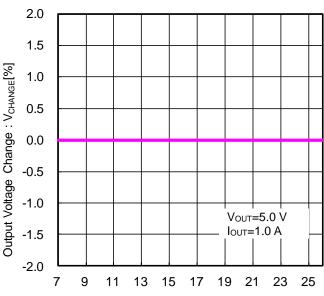


Figure 21. V<sub>OUT</sub> Line Regulation

VIN Input Voltage: VIN[V]

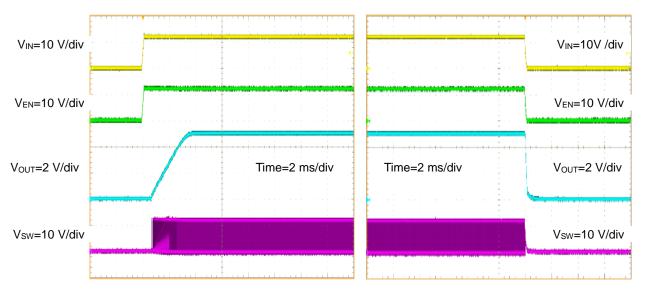


Figure 22. Start-up Waveform ( $V_{IN}=V_{EN}$ )  $I_{OUT}=1.0~A$ 

Figure 23. Shutdown Waveform (V<sub>IN</sub>=V<sub>EN</sub>) I<sub>OUT</sub>=1.0 A

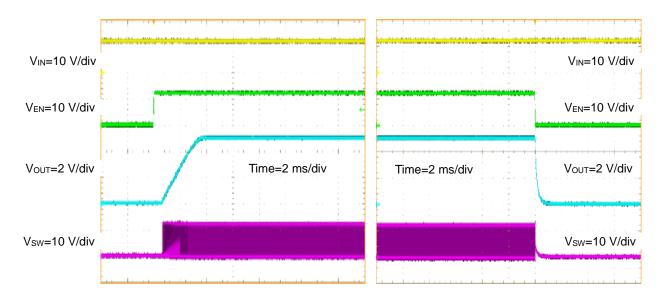


Figure 24. Start-up Waveform (V<sub>EN</sub>=0 V to 5 V)  $I_{OUT}$ =1.0 A

Figure 25. Shutdown Waveform (V<sub>EN</sub>=5 V to 0 V) I<sub>OUT</sub>=1.0 A

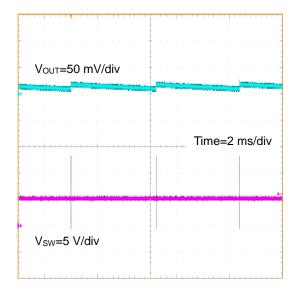


Figure 26.  $V_{OUT}$  Ripple ( $V_{IN}$ =12 V,  $V_{OUT}$ = 5 V,  $I_{OUT}$ =0 A,  $C_{OUT}$ =10  $\mu$ Fx3)

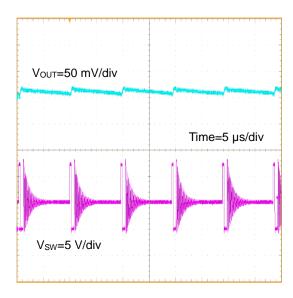


Figure 27. Vout Ripple (VIN=12 V, Vout=5 V, lout=10 mA, Cout=10  $\mu$ Fx3)

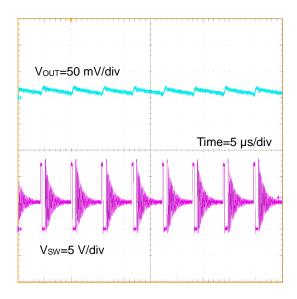


Figure 28. Vout Ripple (VIN=12 V, VOUT=5 V, IOUT=20 mA, COUT=10  $\mu$ Fx3)

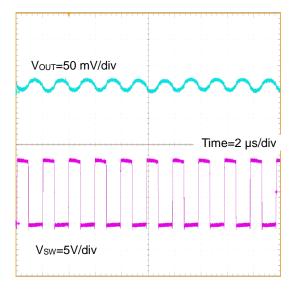


Figure 29. VouT Ripple (VIN=12 V, VouT=5 V, IouT=1 A, CouT=10  $\mu$ Fx3)

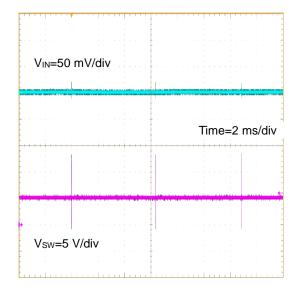


Figure 30. V<sub>IN</sub> Ripple (V<sub>IN</sub>=12 V, V<sub>OUT</sub>=5 V, I<sub>OUT</sub>=0 A)

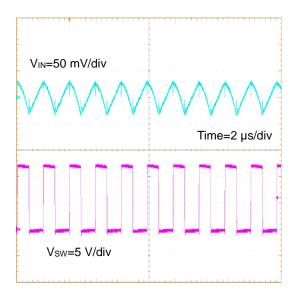


Figure 31. V<sub>IN</sub> Ripple (V<sub>IN</sub>=12 V, V<sub>OUT</sub>=5 V, I<sub>OUT</sub>=1 A)

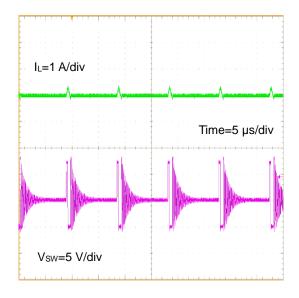


Figure 32. Switching Waveform (VIN=12 V, VOUT=5 V, IOUT=10 mA)

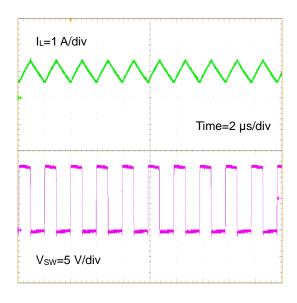


Figure 33. Switching Waveform (V<sub>IN</sub>=12 V, V<sub>OUT</sub>=5 V, I<sub>OUT</sub>=1 A)

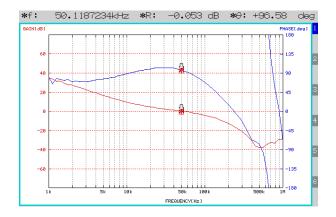


Figure 34. Loop Response (VIN=12 V, VOUT=5 V, IOUT=1 A, COUT=Ceramic10  $\mu$ Fx3)

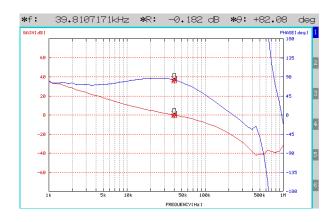


Figure 35. Loop Response ( $V_{IN}$ =12 V,  $V_{OUT}$ =3.3 V,  $I_{OUT}$ =1 A,  $C_{OUT}$ =Ceramic10  $\mu$ Fx3)

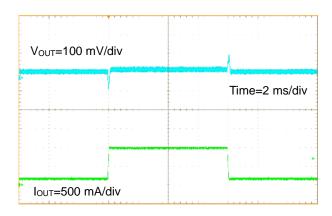


Figure 36. Load Transient Response  $I_{OUT} = 0.2 A - 1 A$ ( $V_{IN}=12 V$ ,  $V_{OUT}=5 V$ ,  $C_{OUT}=Ceramic10 \mu Fx3$ )

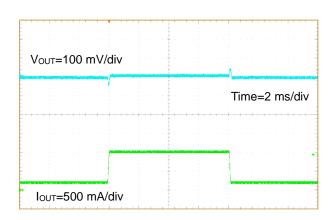


Figure 37. Load Transient Response  $I_{OUT}$  =0.2 A – 1 A ( $V_{IN}$ =12 V,  $V_{OUT}$ =3.3 V,  $V_{OUT}$ =Ceramic10  $V_{IN}$ =3.3 V,  $V_{OUT}$ =3.3 V,  $V_{OUT}$ =3.3 V,  $V_{OUT}$ =4.3

#### **Function Description**

#### 1. DC/DC converter operation

BD9E104FJ is a synchronous rectifying step-down switching regulator that achieves faster transient response by employing current mode PWM control system. It utilizes switching operation in PWM (Pulse Width Modulation) mode for heavier load, while it utilizes SLLM<sup>TM</sup> (Simple Light Load Mode) control for lighter load to improve efficiency.

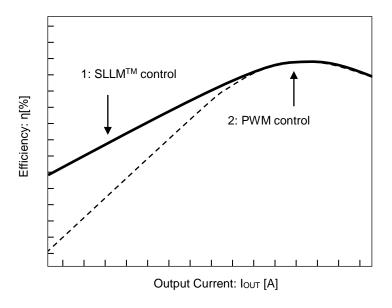


Figure 38. Efficiency (SLLM<sup>TM</sup> control and PWM control)

#### 1: SLLM<sup>TM</sup> control

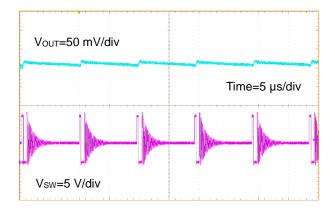


Figure 39. SW Waveform (1: SLLM<sup>TM</sup> control)  $(V_{IN}=12 \text{ V}, V_{OUT}=5.0 \text{ V}, I_{OUT}=10 \text{ mA})$ 

#### 2: PWM control

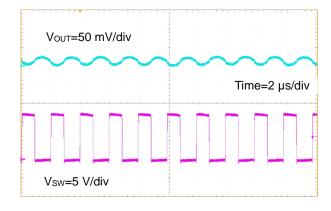


Figure 40. SW Waveform (2: PWM control) (V<sub>IN</sub>= 12 V, V<sub>OUT</sub>=5.0 V, I<sub>OUT</sub>=1 A)

#### **Function Description-continued**

#### **Enable Control**

The IC shutdown can be controlled by the voltage applied to the EN pin. When the EN pin voltage reaches 2.5 V (Min), the internal circuit is activated and the IC starts up. To enable shutdown control with the EN pin, set the shutdown interval (Low level interval of EN) must be set to 100 µs or longer.

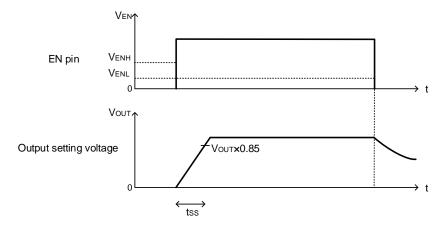


Figure 41. Timing Chart with Enable Control

#### **Protective Functions**

The protective circuits are intended for prevention of damage caused by unexpected accidents. Do not use them for continuous protective operation.

#### **Short Circuit Protection (SCP)**

The short circuit protection block compares the FB pin voltage with the internal reference voltage VREF. When the FB pin voltage has fallen below 0.56 V (Typ) and remained there for 0.9 ms (Typ), SCP stops the operation for 14.4 ms (Typ) and subsequently initiates a restart.

Table 1. Short Circuit Protection Function EN pin FB pin **Short Circuit Protection** Switching Frequency 0.30 V (Typ)≥FB 142.5 kHz (Typ) 2.5 V or higher 0.30 V (Typ)< FB≤0.56 V (Typ) Enabled 285 kHz (Typ) FB>0.56 V (Typ) 570 kHz (Typ)

Disabled OFF 0.8 V or lower

2.5ms (Tvp)  $I_{OUT} \times 0.85$ SCP detection time SCP detection time 0.9ms (Typ) <u>∠</u> 0.9ms (Typ) 0.8V FB terminal SCP threshold voltage 0.56 V (Typ) LOW LOW IC internal SCP signal 14.4ms (Typ)

Figure 42. Short Circuit Protection Function (SCP) Timing Chart

Soft Start

#### **Function Description - continued**

#### (2) Under Voltage Lockout Protection (UVLO)

The under voltage lockout protection circuit monitors the VIN pin voltage. The operation enters standby when the VIN pin voltage is 6.4 V (Typ) or lower. The operation starts when the VIN pin voltage is 6.6 V (Typ) or higher.

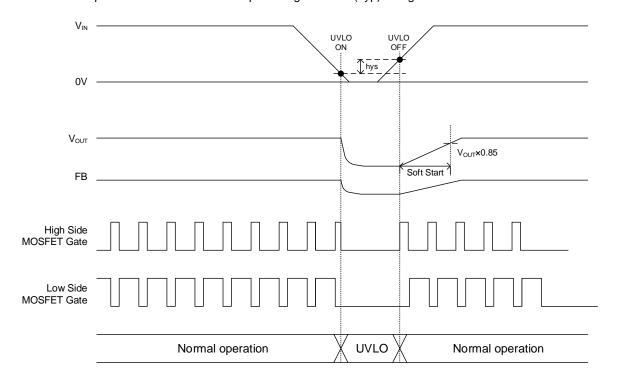


Figure 43. UVLO Timing Chart

#### (3) Thermal Shutdown Function (TSD)

This is the thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. However, if the rating is exceeded for a continued period and the junction temperature (Tj) rises to 175 °C (Typ) or more, the TSD circuit will operate and turn OFF the output MOSFET. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation. Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

# (4) Over Current Protection Function (OCP)

The Over Current Protection Function observes the current flowing in High side MOSFET by switching cycle and when it detects over flow current, it limits ON duty and protects by dropping output voltage.

#### (5) Over Voltage Protection Function (OVP)

Over Voltage Protection Function (OVP) compares the FB pin voltage with internal reference voltage VREF and when the FB pin voltage exceeds 1.04 V (Typ), the OVP function turns off the output MOSFET. When the output voltage drops, the device returns to normal operation with hysteresis.

# **Application Example**

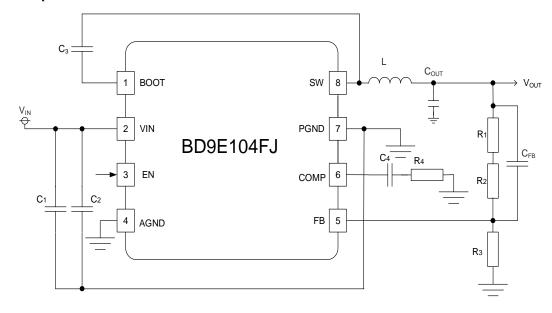


Figure 44. Application Circuit

Table 2. Recommendation Circuit Constants

		<u> </u>	2111
V <sub>IN</sub>	1:	2 V	24 V
V <sub>OUT</sub>	5 V	3.3 V	12 V
C <sub>1</sub> <sup>(Note 1)</sup>	10 μF	10 μF	10 μF
C <sub>2</sub> <sup>(Note 2)</sup>	0.1 μF	0.1 μF	0.1 μF
C <sub>3</sub> <sup>(Note 3)</sup>	0.1 μF	0.1 μF	0.1 μF
L	6.8 µH	6.8 µH	22 µH
R <sub>1</sub>	0 Ω	0 Ω	20 kΩ
R <sub>2</sub>	430 kΩ	470 kΩ	120 kΩ
R <sub>3</sub>	82 kΩ	150 kΩ	10 kΩ
R <sub>4</sub>	82 kΩ	56 kΩ	240 kΩ
C <sub>FB</sub>	12 pF	12 pF	33 pF
C <sub>4</sub>	390 pF	470 pF	2200 pF
Cout <sup>(Note 4)</sup>	Ceramic 10 µF×3	Ceramic 10 µFx3	Ceramic 10 µFx3

<sup>(</sup>Note 1) For capacitance of input capacitor, take temperature characteristics, DC bias characteristics, etc. into consideration to set minimum value no less than 4.7 μF.

<sup>(</sup>Note 2) In order to reduce the influence of high frequency noise, arrange the 0.1 µF ceramic capacitor as close as possible to the VIN pin.

<sup>(</sup>Note 3) Connect a 0.1 µF bootstrap capacitor between the SW pin and the BOOT pin.

<sup>(</sup>Note 4) In case capacitance value fluctuates due to temperature characteristics, DC bias characteristics, etc. of output capacitor, crossover frequency may fluctuate. When selecting a capacitor, confirm the characteristics of the capacitor in its datasheet. Also, please use ceramic type capacitors for output capacitor.

#### **Selection of Components Externally Connected**

About the application except the recommendation, please contact us.

#### 1. Output LC Filter

The DC/DC converter requires an LC filter for smoothing the output voltage in order to supply a continuous current to the load. In BD9E104FJ, IL ripple current flowing through the inductor is returned to the IC for SLLM<sup>TM</sup> control. Use an inductor having the recommended value because the feedback ripple current to the IC is designed to operate optimally when the inductance is the recommended value.

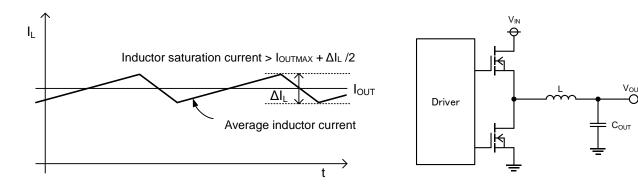


Figure 45. Waveform of Current through Inductor

Figure 46. Output LC Filter Circuit

Computation with V<sub>IN</sub>=12 V, V<sub>OUT</sub>=5 V, L=6.8 µH, and switching frequency f<sub>OSC</sub>=570 kHz, the method is as below.

Inductor ripple current

$$\Delta I_L = V_{OUT} \times (V_{IN} - V_{OUT}) \times \frac{1}{V_{IN} \times f_{OSC} \times L} = 752$$
 [mA]

Also for saturation current of inductor, select the one with larger current than the total of maximum output current and 1/2 of inductor ripple current  $\Delta I_L$ 

Output capacitor  $C_{\text{OUT}}$  affects output ripple voltage characteristics. Select output capacitor  $C_{\text{OUT}}$  so that necessary ripple voltage characteristics are satisfied.

Output ripple voltage can be expressed in the following method.

$$\Delta V_{RPL} = \Delta I_L \times (R_{ESR} + \frac{1}{8 \times C_{OUT} \times F_{OSC}})$$
 [V]

R<sub>ESR</sub> is the serial equivalent series resistance here.

With  $C_{OUT}=30 \mu F$ ,  $R_{ESR}=10 m\Omega$  the output ripple voltage is calculated as below.

$$\Delta V_{RPL} = 0.75 \times (10m + \frac{1}{8 \times 30\mu \times 570k}) = 13$$
 [mV]

# **Selection of Components Externally Connected - continued**

\*Be careful of total capacitance value, when additional capacitor  $C_{LOAD}$  is connected to output capacitor  $C_{OUT}$ . Use maximum additional capacitor  $C_{LOAD}$  (Max) condition which satisfies the following method.

Maximum starting inductor ripple current I<sub>L\_START</sub> < Over current limit 2.1 A (Min)

Maximum starting inductor ripple current I<sub>L\_START</sub> can be expressed in the following method.

$$I_{L\_START} = Maximum starting output current (Ioutmax) + Charge current to output capacitor(Icap) +  $\frac{\Delta IL}{2}$$$

Charge current to output capacitor ICAP can be expressed in the following method.

$$I_{CAP} = \frac{(C_{OUT} + C_{LOAD}) \times V_{OUT}}{t_{SS}}$$
 [A]

Computation with  $V_{IN}=12$  V,  $V_{OUT}=5$  V, L=6.8  $\mu$ H,  $I_{OUTMAX}=1$  A (Max), switching frequency  $f_{OSC}=484$  kHz (Min), Output capacitor  $C_{OUT}=30$   $\mu$ F, Soft Start Time  $t_{SS}=1.2$  ms (Min), the method is as below.

$$C_{LOAD}(Max) \leq \frac{(2.1 - I_{OUTMAX} - \frac{\Delta I_L}{2}) \times t_{SS}}{V_{OUT}} - C_{OUT} = 127$$
 [µF]

Confirm maximum starting inductor ripple current less than 2.1 A on actual equipment.

#### 2. Output Voltage Set Point

The output voltage value can be set by the feedback resistance ratio.

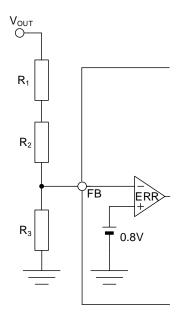


Figure 47. Feedback Resistor Circuit

$$V_{OUT} = \frac{R_1 + R_2 + R_3}{R_3} \times 0.8$$
 [V]

\*Minimum pulse is 250 ns for BD9E104FJ.
Use input/output condition which satisfies the following method.

$$250ns \le \frac{V_{OUT}}{V_W} \times 1.75$$
 [µs]

# **Selection of Components Externally Connected - continued**

# 3. Phase Compensation

A current mode control buck DC/DC converter is a two-pole, one-zero system. Two-pole formed by an error amplifier and load and one zero point added by phase compensation. The phase compensation resistor  $R_4$  determines the crossover frequency  $f_{CRS}$  where the total loop gain of the DC/DC converter is 0 dB. High value for this crossover frequency  $f_{CRS}$  provides a good load transient response characteristic but inferior stability. Conversely, specifying a low value for the crossover frequency  $f_{CRS}$  greatly stabilizes the characteristics but the load transient response characteristic is impaired.

#### (1) Selection of Phase Compensation Resistor R4

The phase compensation resistance R<sub>4</sub> can be determined by using the following equation.

$$R_4 = \frac{2\pi \times V_{OUT} \times f_{CRS} \times C_{OUT}}{V_{FB} \times G_{MP} \times G_{MA}} \qquad [\Omega]$$

Where:

 $V_{OUT}$  is the output voltage (5 V (Typ))

 $f_{CRS}$  is the crossover frequency [Hz]

*Cour* is the output capacitance [F]

 $V_{FB}$  is the feedback reference voltage (0.8 V (Typ))

 $G_{MP}$  is the current sense gain (7 A/V (Typ))

 $G_{MA}$  is the error amplifier transconductance (82  $\mu$ A/V (Typ))

#### (2) Selection of phase compensation capacitance C<sub>4</sub>

For stable operation of the DC/DC converter, inserting a zero point at 1/6 of the zero crossover frequency cancels the phase delay due to the pole formed by the load often provides favorable characteristics.

The phase compensation capacitance C<sub>4</sub> can be determined by using the following equation.

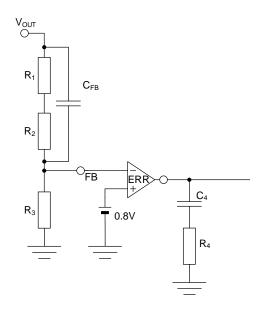
$$C_4 = \frac{1}{2\pi \times R_4 \times f_Z} \qquad [F]$$

Where:

 $f_Z$  is Zero point inserted

#### (3) Loop stability

In order to ensure stability of DC/DC converter, confirm there is enough phase margin on actual equipment. Under the worst condition, it is recommended to ensure phase margin is  $45^{\circ}$  or more. The feed forward capacitor  $C_{FB}$  is used for the purpose of forming a zero point together with the resistor  $R_1$  and  $R_2$  to increase the phase margin within the limited frequency range.





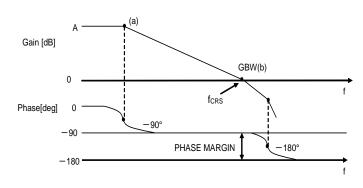


Figure 49. Bode Plot

#### **PCB Layout Design**

PCB layout design for DC/DC converter power supply IC is as important as the circuit design. Appropriate layout can avoid various problems caused by power supply circuit. Figure 50-a to 50-c show the current path in a buck DC/DC converter circuit. The Loop1 in Figure 50-a is a current path when High Side switch is ON and Low Side switch is OFF, the Loop2 in Figure 50-b is when High Side switch is OFF and Low Side switch is ON. The thick line in Figure 50-c shows the difference between Loop1 and Loop2. The current in thick line changes sharply each time the switching element High Side and Low Side switch change from OFF to ON, and vice versa. These sharp changes induce several harmonics in the waveform. Therefore, the loop area of thick line that is consisted by input capacitor and IC should be as small as possible to minimize noise. For more detail, refer to application note of switching regulator series "PCB Layout Techniques of Buck Converter".

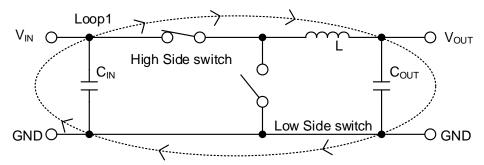


Figure 50-a. Current path when High Side switch = ON, Low Side switch = OFF

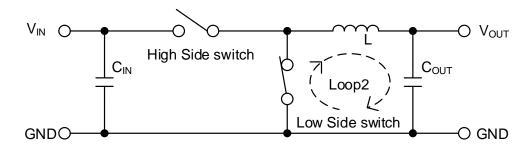


Figure 50-b. Current Path when High Side switch = OFF, Low Side switch = ON

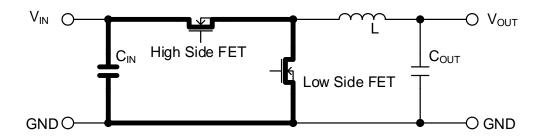
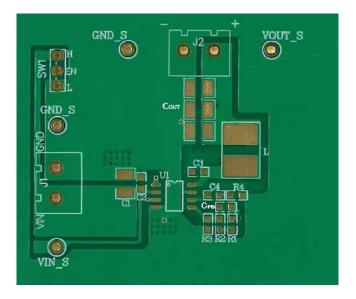


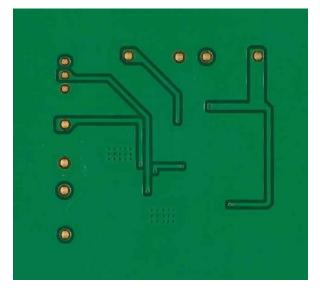
Figure 50-c. Difference of Current and Critical Area in Layout

# **PCB Layout Design - continued**

Accordingly, design the PCB layout with particular attention paid to the following points.

- Provide the input capacitor close to the VIN pin of the IC as possible on the same plane as the IC.
- If there is any unused area on the PCB, provide a copper foil plane for the ground node to assist heat dissipation from the IC and the surrounding components.
- Switching nodes such as SW are susceptible to noise due to AC coupling with other nodes. Trace to the coil as thick and short as possible.
- Provide lines connected to the FB pin and the COMP pin as far from the SW node.
- Provide the output capacitor away from the input capacitor in order to avoid the effect of harmonic noise from the input.





Top Layer Bottom Layer

Figure 51. Example of Sample Board Layout Pattern

# I/O Equivalence Circuit

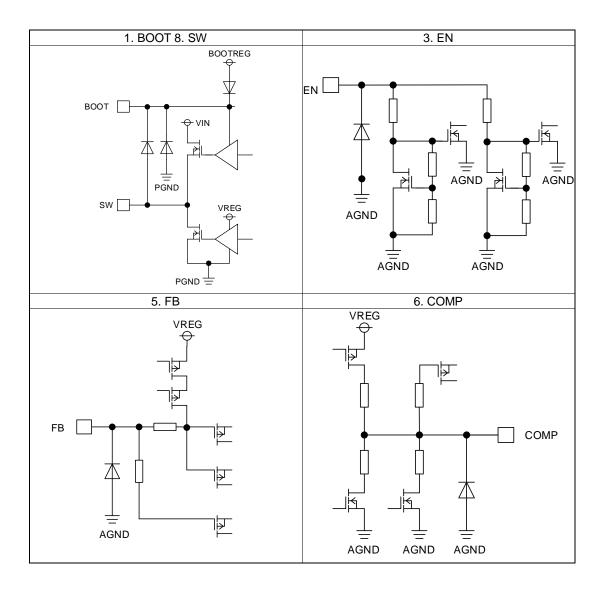


Figure 52. I/O Equivalence Circuit

#### **Operational Notes**

#### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

#### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition. However, pins that drive inductive loads (e.g. motor driver outputs, DC-DC converter outputs) may inevitably go below ground due to back EMF or electromotive force. In such cases, the user should make sure that such voltages going below ground will not cause the IC and the system to malfunction by examining carefully all relevant factors and conditions such as motor characteristics, supply voltage, operating frequency and PCB wiring to name a few.

# 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

#### 6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

#### 7. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

#### 8. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

# 9. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

# 10. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

#### **Operational Notes - continued**

#### 11. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

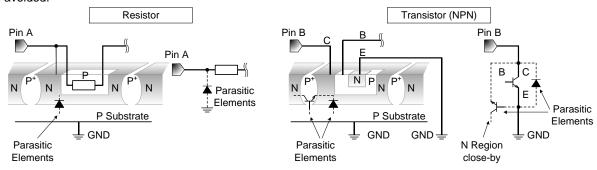


Figure 53. Example of monolithic IC structure

#### 12. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

#### 13. Area of Safe Operation (ASO)

Operate the IC such that the output voltage, output current, and the maximum junction temperature rating are all within the Area of Safe Operation (ASO).

#### 14. Thermal Shutdown Circuit(TSD)

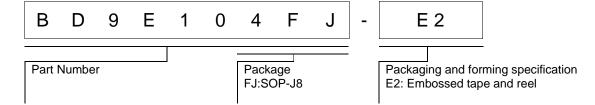
This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's maximum junction temperature rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF power output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

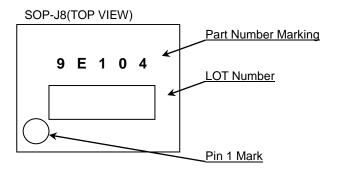
#### 15. Over Current Protection Circuit (OCP)

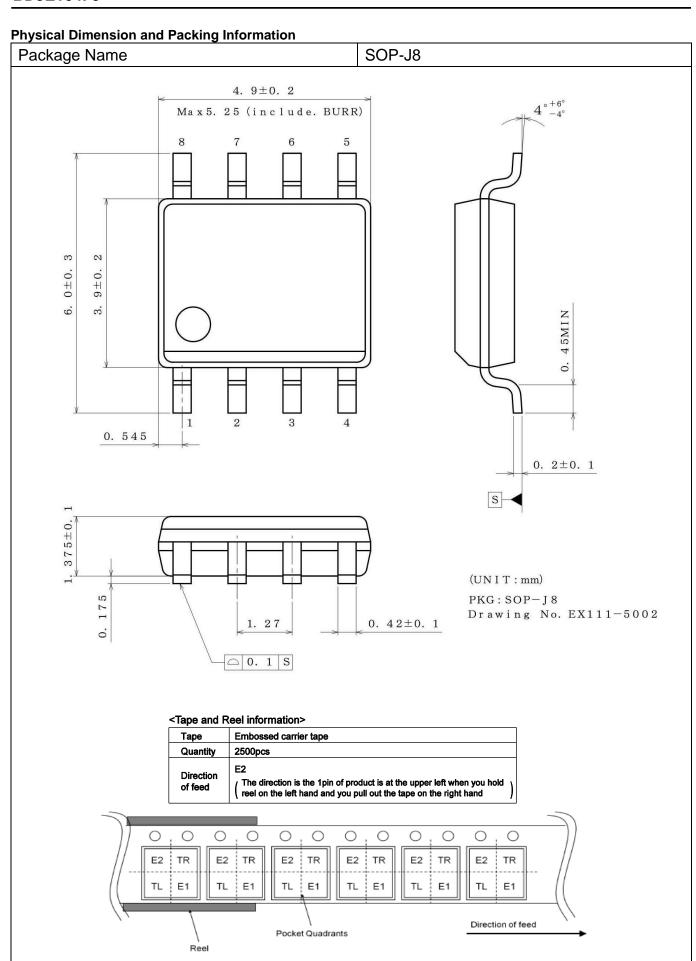
This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

# **Ordering Information**



# **Marking Diagram**





**Revision History** 

Date	Revision	Changes
11.Dec.2017	001	New Release

# **Notice**

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	CLASSIII	OL ACOM	CLASS II b	ОГУСОШ
	CLASSIV	CLASSⅢ	CLASSIII	CLASSⅢ

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- 4. The Products are not subject to radiation-proof design.
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# BD9E104FJ - Web Page

Part Number	BD9E104FJ
Package	SOP-J8
Unit Quantity	2500
Minimum Package Quantity	2500
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes